

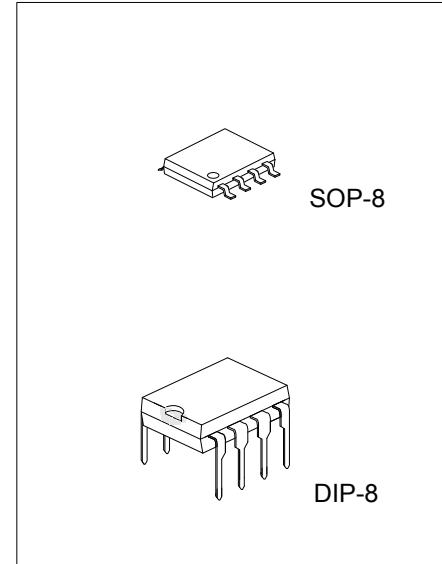
DUAL DIFFERENTIAL COMPARATOR

■ DESCRIPTION

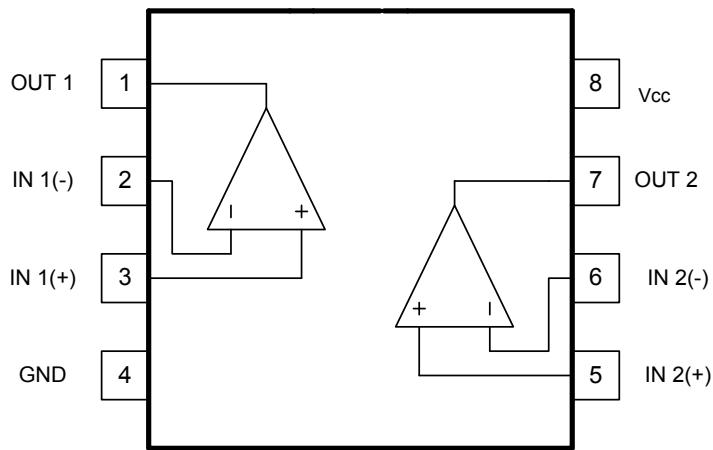
The HGsemi LM293 consists of two independent voltage comparators, designed specifically to operate from a single power supply over a wide voltage range.

■ FEATURES

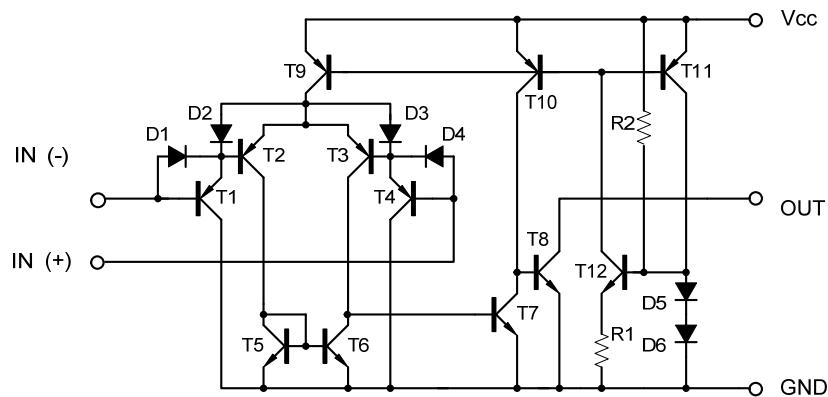
- * Single or dual supply operation.
- * Wide operating supply range ($V_{CC}=2V \sim 36V$ or $\pm 1 \sim \pm 18V$)
- * Input common-mode voltage includes ground.
- * Low supply current drain $I_{CC}=0.8mA$ (Typical).
- * Low input bias current $I_{BIAS}=25nA$ (Typical).
- * Output compatible with TTL, DTL, and CMOS logic system.



■ PIN DESCRIPTION



■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | RATINGS | UNIT |
|-----------------------------|---------------|----------------|------|
| Supply Voltage | V_{CC} | ± 18 or 36 | V |
| Differential Input Voltage | $V_{I(DIFF)}$ | 36 | V |
| Input Voltage | V_{IN} | -0.3 ~ +36 | V |
| Power Dissipation | DIP-8 | 600 | mW |
| | SOP-8 | 420 | mW |
| | | | |
| Operating Temperature Range | T_{OPR} | -20 ~ +85 | °C |
| Storage Temperature Range | T_{STG} | -65 ~ +150 | °C |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

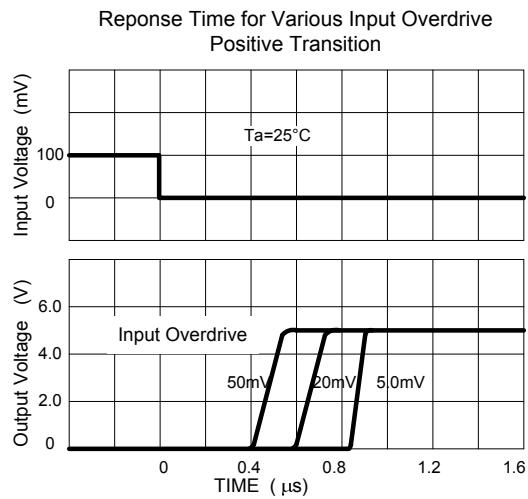
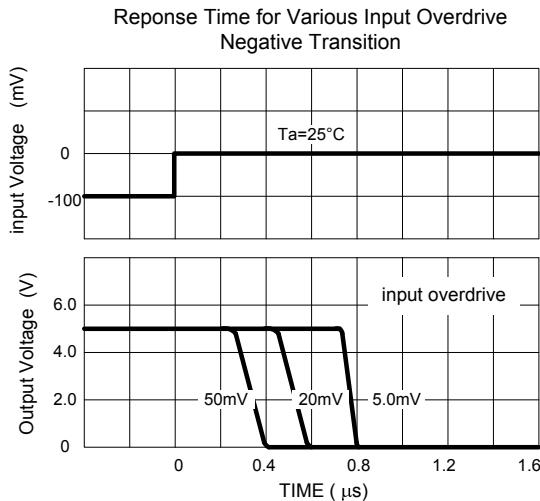
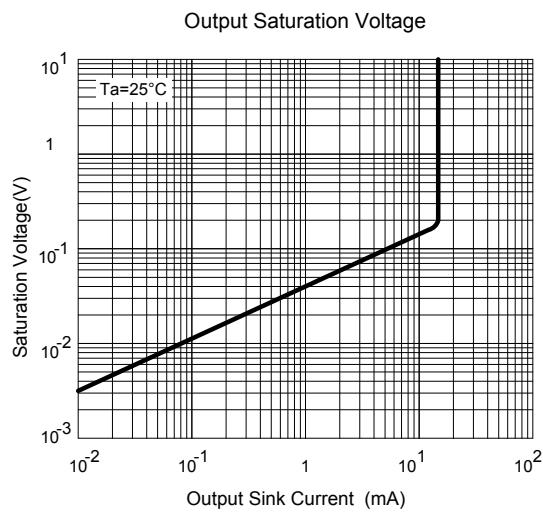
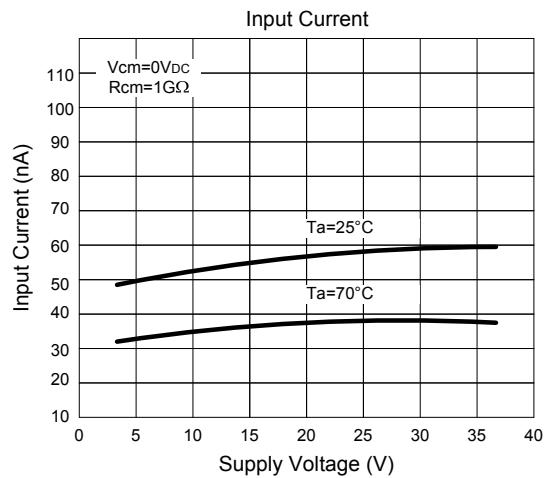
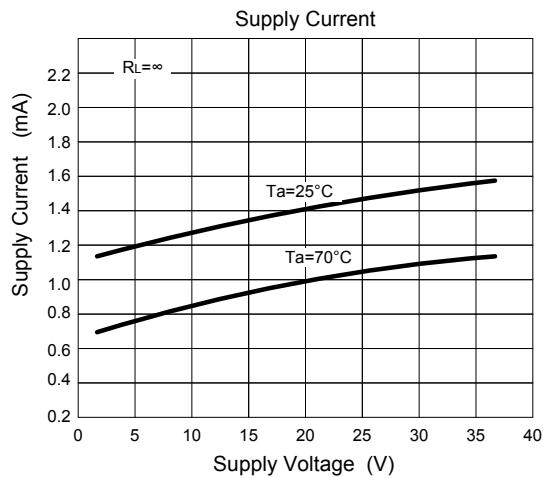
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS

($V_{CC}=5.0V$, $T_a=25^{\circ}C$, All voltage referenced to GND unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------|---------------|-----------------------------------------------------------------------------|--------------|------|--------------|---------|
| Input Offset Voltage | $V_{I(OFF)}$ | $V_{CM}=0V$ to $V_{CC}-1.5V$ $V_{O(P)}=1.4V$, $R_S=0\Omega$ | | 1.0 | 5.0 | mV |
| Output Saturation Voltage | V_{SAT} | $V_I(-)>1V$, $V_I(+)=0V$, $I_{SINK}=4mA$ | | 160 | 400 | mV |
| Input Common Mode Voltage | $V_{I(CM)}$ | $V_{CC}=30V$ | 0 | | $V_{CC}-1.5$ | V |
| Large Signal Voltage Gain | G_V | $V_{CC}=15V$, $R_L \geq 15k\Omega$ | 50 | 200 | | V/mV |
| Power Supply Current | I_{CC} | $R_L=\infty$, $V_{CC}=30V$ | | 0.8 | 2.5 | mA |
| | | $R_L=\infty$ | | 0.6 | 1.0 | mA |
| Input Offset Current | $I_{I(OFF)}$ | | | 5 | 50 | nA |
| Input Bias Current | $I_{I(BIAS)}$ | | | 65 | 250 | nA |
| Output Sink Current | $I_{O(SINK)}$ | $V_I(-)>1V$, $V_I(+)=0V$, $V_o(p)<1.5V$ | 6 | 18 | | mA |
| Output Leakage Current | $I_{O(LEAK)}$ | $V_I(+)=1V$, $V_I(-)=0$ | $V_o(p)=5V$ | 0.1 | | nA |
| | | | $V_o(p)=30V$ | | 1.0 | μA |
| Large Signal Response Time | t_R | $V_{IN}=TTL$ logic swing $V_{REF}=1.4V$, $V_{RL}=5V$, $R_L=5.1k\Omega$ | | 350 | | ns |
| Response Time | t_R | $V_{RL}=5V$, $R_L=5.1k\Omega$ | | 1400 | | ns |

■ TYPICAL CHARACTERISTICS



单击下面可查看定价，库存，交付和生命周期等信息

[>>HGSEMI \(华冠\)](#)